
Pin Definition:

- | | |
|-------------|------------|
| 1. Source 1 | 8. Drain 1 |
| 2. Gate 1 | 7. Drain 1 |
| 3. Source 2 | 6. Drain 2 |
| 4. Gate 2 | 5. Drain 2 |

MOSFET PRODUCT SUMMARY

	V _{DS} (V)	R _{DS(on)} (mΩ)	I _D (A)
N-Channel	30	28 @ V _{GS} = 10V	6.5
		42 @ V _{GS} = 4.5V	5.0
P-Channel	-30	65 @ V _{GS} = -10V	-4.2
		90 @ V _{GS} = -4.5V	-3.5

Features

- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

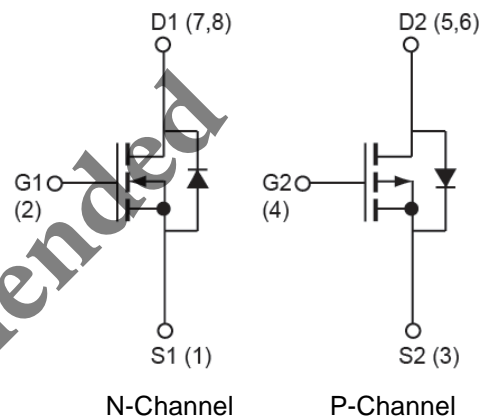
Application

- Load Switch
- PA Switch

Ordering Information

Part No.	Package	Packing
TSM4539DCS RLG	SOP-8	2.5Kpcs / 13" Reel

Note: "G" denote for Halogen Free Product

Block Diagram

MOSFET Absolute Maximum Rating (T_A=25°C unless otherwise noted)

Parameter	Symbol	N-CH Limit	P-CH Limit	Unit
Drain-Source Voltage	V _{DS}	30	-30	V
Gate-Source Voltage	V _{GS}	±20	±20	V
Continuous Drain Current, V _{GS}	I _D	6.5	-4.2	A
Pulsed Drain Current,	I _{DM}	28	-20	A
Drain-Source Diode Forward Current	I _S	2.5	-1.9	A
Power Dissipation @ Ta = 25°C	P _D	2.1	2.1	W
Operating Junction Temperature	T _J	150		°C
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 ~ +150		°C

Thermal Performance

Parameter	Symbol	N-CH Limit	P-CH Limit	Unit
Junction to Ambient Thermal Resistance	R _{θJA}	62.5	62.5	°C/W
Junction to Lead Thermal Resistance	R _{θJL}	40	40	°C/W

Notes:

- Pulse width limited by the Maximum junction temperature
- Surface Mounted on FR4 Board using 1 inch sq pad size, t ≤ 5sec.
- Surge Applied at Rated Load Conditions, Half-Wave, Single Phase, 60Hz.

Electrical Specifications (T_A=25°C unless otherwise noted)

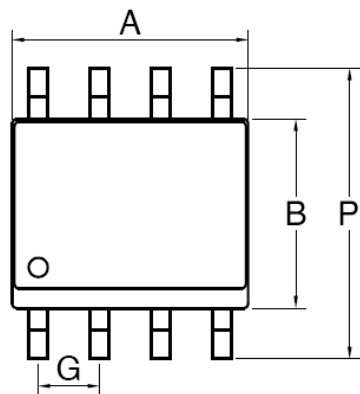
Parameter	Conditions	Symbol	Min	Typ	Max	Unit	
Static							
Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	BV _{DSS}	N-CH	30	--	--	V
	V _{GS} =0V, I _D =-250μA		P-CH	-30	--	--	
Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	V _{GS(TH)}	N-CH	1.0	1.4	3.0	V
	V _{DS} =V _{GS} , I _D =-250μA		P-CH	-1.0	-1.5	-3.0	
Gate Body Leakage	V _{GS} =±20V, V _{DS} =0V	I _{GSS}	N-CH	--	--	±100	nA
	V _{GS} =±20V, V _{DS} =0V		P-CH	--	--	±10	
Zero Gate Voltage Drain Current	V _{DS} =24V, V _{GS} =0V	I _{DSS}	N-CH	--	--	1	μA
	V _{DS} =-24V, V _{GS} =0V		P-CH	--	--	-1	
Drain-Source On-State Resistance ^a	V _{GS} =10V, I _D =6.5A	R _{DS(ON)}	N-CH	--	23	28	mΩ
	V _{GS} =-10V, I _D =-4.2A		P-CH	--	50	65	
	V _{GS} =4.5V, I _D =5A		N-CH	--	35	42	
	V _{GS} =-4.5V, I _D =-3.5A		P-CH	--	82	90	
Dynamic^b							
Total Gate Charge	N-Channel V _{DS} =10V, I _D =1A, V _{GS} =10V	Q _g	N-CH	--	7	--	nC
			P-CH	--	9.7	--	
Gate-Source Charge	P-Channel V _{DS} =-15V, I _D =-5.2A, V _{GS} =-10V	Q _{gs}	N-CH	--	1.6	--	nC
			P-CH	--	1.6	--	
Gate-Drain Charge	V _{DS} =-15V, I _D =-5.2A, V _{GS} =-10V	Q _{gd}	N-CH	--	1.0	--	nC
			P-CH	--	1.3	--	
Input Capacitance	N-Channel V _{DS} =15V, V _{GS} =0V, f=1.0MHz	C _{iss}	N-CH	--	610	--	pF
			P-CH	--	100	--	
Output Capacitance	P-Channel V _{DS} =-15V, V _{GS} =0V, f=1.0MHz	C _{oss}	N-CH	--	77	--	pF
			P-CH	--	551	--	
Reverse Transfer Capacitance	V _{DS} =-15V, V _{GS} =0V, f=1.0MHz	C _{rss}	N-CH	--	90	--	pF
			P-CH	--	60	--	
Switching^b							
Turn-On Delay Time	N-Channel V _{DD} =15V, I _D =1A, V _{GEN} =10V, R _G =6Ω	t _{d(on)}	N-CH	--	7	--	nS
			P-CH	--	6.2	--	
Turn-On Rise Time	V _{DD} =15V, I _D =1A, V _{GEN} =10V, R _G =6Ω	t _r	N-CH	--	10	--	nS
			P-CH	--	6.2	--	
Turn-Off Delay Time	P-Channel V _{DD} =-15V, I _D =-1A, V _{GEN} =-10V, R _G =6Ω	t _{d(off)}	N-CH	--	16	--	nS
			P-CH	--	26	--	
Turn-Off Fall Time	V _{DD} =-15V, I _D =-1A, V _{GEN} =-10V, R _G =6Ω	t _f	N-CH	--	7	--	nS
			P-CH	--	5.5	--	
Diode Forward Voltage	I _S =1A, V _{GS} =0V	V _{SD}	N-CH	--	--	1.0	V
	I _S =-1.9A, V _{GS} =0V		P-CH	--	--	-1.3	

Notes:

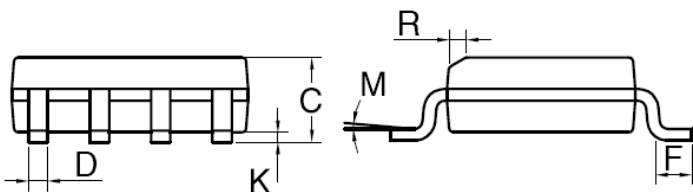
a. Pulse test: PW ≤300μS, duty cycle ≤2%

b. For DESIGN AID ONLY, not subject to production testing.

SOP-8 Mechanical Drawing



SOP-8 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX.
A	4.80	5.00	0.189	0.196
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27BSC		0.05BSC	
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019



Not Recommended

Not Recommended

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